

# 1MBI50U4F-120L-50

**IGBT Modules** 

# IGBT MODULE (U series) 1200V / 50A / 1 in one package

#### ■ Features

High speed switching Voltage drive Low Inductance module structure

#### ■ Applications

Inverter DB for Motor Drive AC and DC Servo Drive Amplifier (DB) Active PFC Industrial machines



#### ■ Maximum Ratings and Characteristics

#### ● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items	ems		Conditions		Maximum ratings	Units	
Collector-Emitter voltage		Vces			1200	V	
Gate-Emitter voltage		V <sub>GES</sub>			±20	V	
Collector current		Ic	Continuous	Tc=25°C	75		
			Continuous	Tc=80°C	50		
		Ic pulse	1ma	Tc=25°C	150	٨	
			1ms	Tc=80°C	100	Α	
		-lc			25		
		-lc pulse	1ms		50		
Collector power dissipation		Pc	1 device		275	W	
Reverse voltage for FWD		VR			1200	V	
Forward current for FWD		IF	Continuous		75	Α	
		IF pulse	1ms		150		
Junction temperature		Tj			+150	°C	
Storage temperature		Tstg			-40~+125	°C	
Isolation voltage	Between terminal and copper base (*1)	Viso	AC : 1min.		2500	VAC	
Screw torque	Mounting (*2)		2.5		2.5	Nima	
	Terminals (*3)	]-			3.5	Nm	

Note \*1: All terminals should be connected together when isolation test will be done.

Note \*2: Recommendable Value : 2.5 to 3.5 Nm (M5 or M6) Note \*3: Recommendable Value : 2.5 to 3.5 Nm (M5)

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#### ● Electrical characteristics (at Tj= 25°C unless otherwise specified)

Items	Symbolo	Conditions	Conditions		Characteristics		
items	Symbols	Conditions		min.	typ.	max.	Units
Zero gate voltage collector current	Ices	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 1200	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 1200V		-	1.0	mA
Gate-Emitter leakage current	Iges	V <sub>CE</sub> = 0V, V <sub>GE</sub> = ±20\	V <sub>CE</sub> = 0V, V <sub>GE</sub> = ±20V		-	200	nA
Gate-Emitter threshold voltage	V <sub>GE (th)</sub>	V <sub>CE</sub> = 20V, I <sub>C</sub> = 50mA		4.5	6.5	8.5	V
	V <sub>CE</sub> (sat)	V <sub>GE</sub> = 15V I <sub>C</sub> = 50A	Tj=25°C	-	2.00	2.15	V
Collector Emitter activation valtage	(terminal)		Tj=125°C	-	2.20	-	
Collector-Emitter saturation voltage	V <sub>CE</sub> (sat)		Tj=25°C	-	1.90	2.05	
	(chip)		Tj=125°C	-	2.10	-	
Input capacitance	Cies	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 10V, f = 1MHz		-	6	-	nF
	ton			-	0.32	1.20	
Turn-on time	tr	.,	1		0.10	0.60	μs
	tr(i)	Vcc = 600V, Ic = 50A Vce = ±15V. Rc = 22	-	0.03	-		
Towns of the co	toff	VGE = £15V, RG = 2211		-	0.41	1.00	
Turn-off time	tf			-	0.07	0.30	
	V <sub>F</sub>		Tj=25°C	-	1.65	2.00	V
Famusand on violations	(terminal)	V <sub>GE</sub> = 0V I <sub>F</sub> = 25A	Tj=125°C	-	1.75	-	
Forward on voltage	V <sub>F</sub>		Tj=25°C	-	1.60	1.85	
	(chip)		Tj=125°C	-	1.70	-	
Reverse Current	IR	V <sub>CE</sub> = 1200V		-	-	1.0	mA
	V <sub>F</sub>		Tj=25°C	-	1.75	1.90	V
F	(terminal)	$V_{GE} = 0V$	Tj=125°C	-	1.90	-	
Forward on voltage	V <sub>F</sub>	I <sub>F</sub> = 75A	Tj=25°C	-	1.60	1.75	
	(chip)		Tj=125°C	-	1.75	-	
Reverse recovery time	trr	I <sub>F</sub> = 75A	, -	-	-	0.35	μs
Lead resistance, terminal-chip(*4)	R lead			-	1.39	-	mΩ

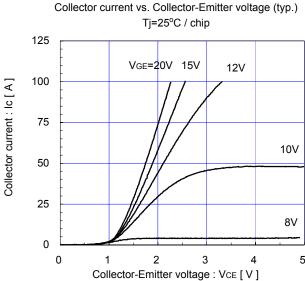
Note \*4: Biggest internal terminal resistance among arm.

#### ● Thermal resistance characteristics

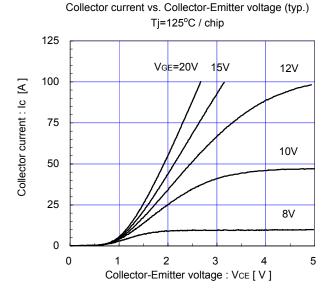
Items	Symbols	Conditions	Characteristics			Units	
items		Conditions	min.	typ.	max.	Ullits	
	Rth(j-c)	IGBT	-	-	0.45		
Thermal resistance (1device)		Inverse Diode	-	-	1.19	°C/W	
		FWD	-	-	0.48	0.48	
Contact thermal resistance	Rth(c-f)	with Thermal Compound (*5)	1	0.05	-		

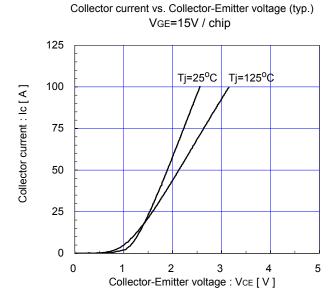
Note  $^{\star}5$ : This is the value which is defined mounting on the additional cooling fin with thermal compound.

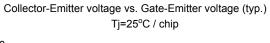
#### ■ Characteristics (Representative)

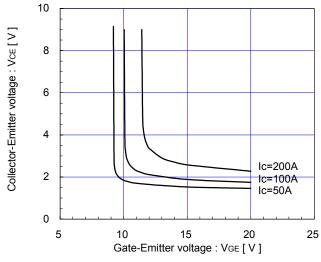


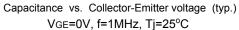


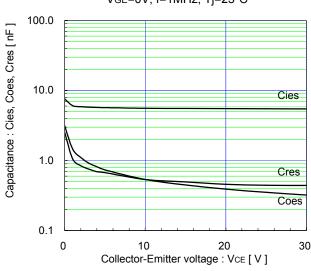




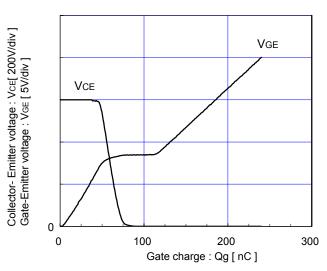


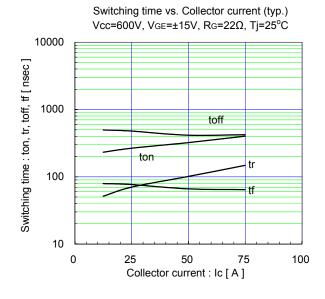


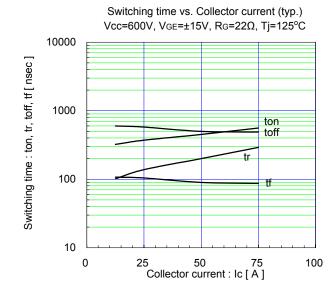


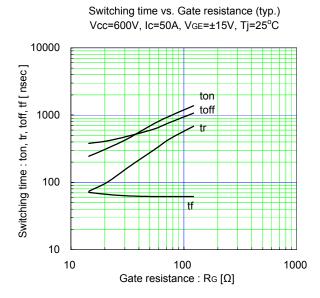


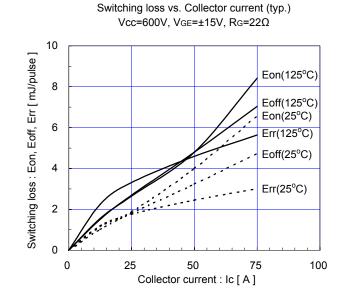
Dynamic Gate charge (typ.) Vcc=600V, Ic=50A, Tj=25°C

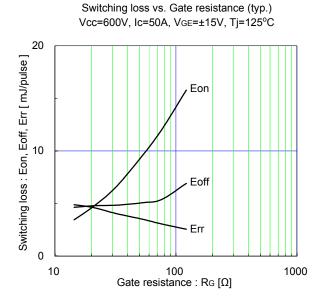


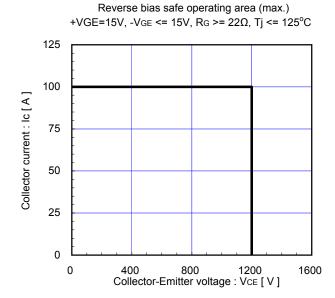




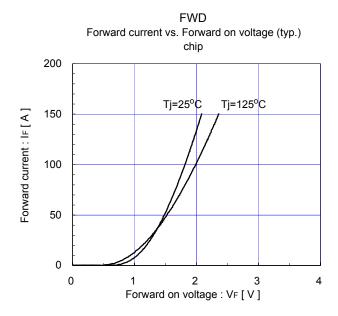


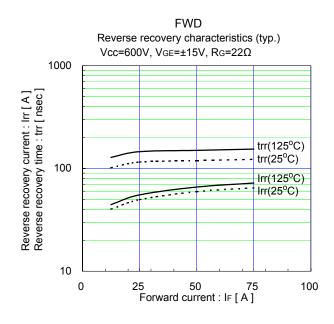


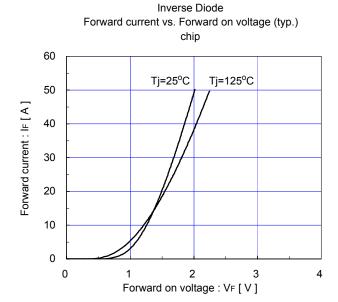


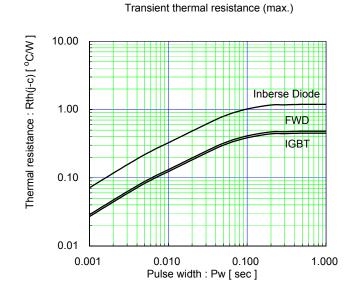


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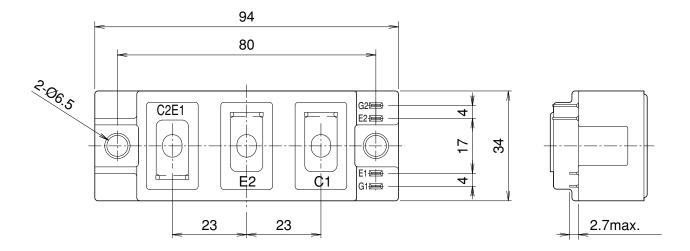


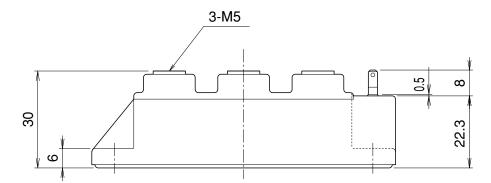




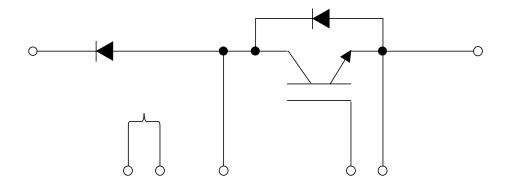


## Outline Drawings, mm





## **■** Equivalent Circuit Schematic



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- OA equipment
- Communications equipment (terminal devices)
- Measurement equipment

Machine tools

becomes faulty.

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